VTS Process Photodiodes

VTS__81, 83, 84

PRODUCT DESCRIPTION

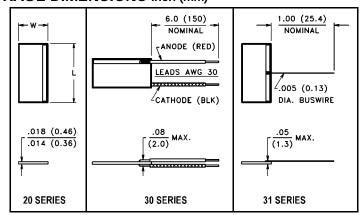
This series of planar, P on N, large area silicon photodiodes is characterized for use in the photovoltaic (unbiased) mode. Their excellent speed and broadband sensitivity makes them ideal for detecting light from a variety of sources such as LEDs, IREDs, flashtubes, incandescent lamps, lasers, etc. Improved shunt resistance minimizes amplifier offset and drift in high gain systems. The solderable contact system on these photodiodes provides a cost effective design solution for many applications.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature:

-40°C to 150°C	Series 20, 31
-40°C to 105°C	Series 30
Operating Temperature:	
-40°C to 125°C	Series 20, 31
-40°C to 105°C	Series 30
Reverse Voltage:	6.0 Volts

PACKAGE DIMENSIONS inch (mm)



CASE 44C ANODE (ACTIVE) SURFACE SHOWN CATHODE IS BACKSIDE

DIMENSIONS	VTS81	VTS83	VTS84
L	.800 (20.32)	.800 (20.32)	.400 (10.16)
W	.400 (10.16)	.200 (5.08)	.200 (5.08)
ACTIVE AREA	.290 ² (187 ²)	.132 ² (85 ²)	.065 ² (42 ²)

ELECTRO-OPTICAL CHARACTERISTICS @ 25°C (See also VTS curves, page 67)

SYMBOL	CHARACTERISTIC TEST CONDITIONS	VTS81		VTS83			VTS84			UNITS		
		1E31 CONDITIONS	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	UNITS
I _{SC}	Short Circuit Current	H = 1000 lux, 2850 K	1.10	1.50		0.5	0.64		0.25	0.33		mA
TC I _{SC}	I _{SC} Temperature Coefficient	H = 1000 Lux, 2850 K		0.20			.20			.20		%/°C
I _D	Dark Current	H = 0, VR = 100 mV		100	500		50	200		40	100	nA
TC I _D	ID Temp. Coefficient	H = 0, VR = 100 mV		+11			+11			+11		%/°C
R _{SH}	Shunt Resistance	H = 0, VR = 10 mV		0.6			1.2			1.5		$M\Omega$
СЈ	Junction Capacitance	H = 0, V = 0 V, 1 MHz		3.5			1.75			1.0		nF
S _R	Sensitivity	@ 400 nm	.18	0.20		0.18	0.20		0.18	0.20		A/W
Re	Responsivity	400 nm, 0.18 A/W		0.34			0.15			0.07		A/(W/cm ²)
TC V _{OC}	Sensitivity @ Peak	925 nm		0.60			0.60			0.60		A/W
t_R/t_F	Response Time @ 1 $k\Omega$ Load	VR = 1 V, 830 nm		6.4			3.4			1.8		µsec
V _{OC}	Open Circuit Voltage	H = 1000 Lux, 2850 K	0.25	0.45		0.25	0.45		0.25	0.45		Volts
TC V _{OC}	V _{OC} Temperature Coefficient	H = 1000 Lux, 2850 K		-2.6			-2.6			-2.6		mV/°C